

TPR 500

500 Watts, 50 Volts, Pulsed Avionics 1030 - 1090 MHz

GENERAL DESCRIPTION

The TPR 500 is a high power COMMON BASE bipolar transistor. It is designed for pulsed systems in the frequency band 1030-1090 MHz. The device has gold thin-film metallization for proven highest MTTF. The transistor includes input prematch for broadband capability. Low thermal resistance package reduces junction temperature, extends life.

ABSOLUTE MAXIMUM RATINGS

Maximum Power Dissipation @ 25°C² 1750 Watts

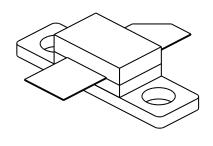
Maximum Voltage and Current

BVces Collector to Base Voltage 60 Volts
BVebo Emitter to Base Voltage 4.0 Volts
Ic Collector Current 40 Amps

Maximum Temperatures

Storage Temperature $- 65 \text{ to} + 150^{\circ}\text{C}$ Operating Junction Temperature $+ 200^{\circ}\text{C}$

CASE OUTLINE 55CX, STYLE 1



ELECTRICAL CHARACTERISTICS @ 25 °C

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Pout Pin Pg η _c VSWR	Power Out Power Input Power Gain Collector Efficiency Load Mismatch Tolerance	F = 1090 MHz $Vcc = 50 Volts$ $PW = 10 µsec$ $DF = 1%$ $F = 1090 MHz$	500 5.2	6.0 35	150 10:1	Watts Watts dB %

BVebo BVces h _{FE} θ j c ²	Emitter to Base Breakdown Collector to Emitter Breakdown DC - Current Gain Thermal Resistance	Ie = 30 mA Ic = 30 mA Ic = 500mA, Vce = 5 V	3.5 55 10		0.1	Volts Volts °C/W
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Note 1: At rated output power and pulse conditions

2: At rated pulse conditions

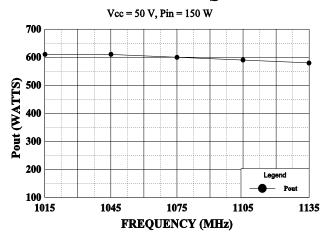
Initial Issue June 1, 1994

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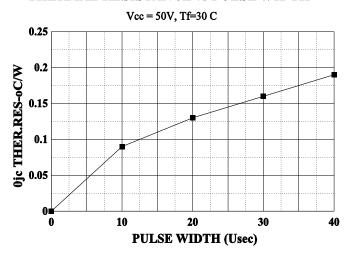
CHz TECHNOLOCY RF-MICROWAVE SILICON POWER TRANSISTORS

TPR500

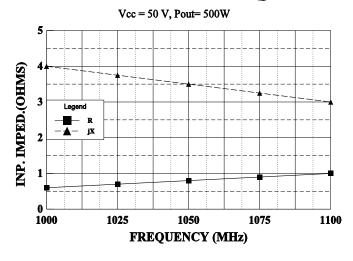
POWER OUTPUT vs FREQUENCY



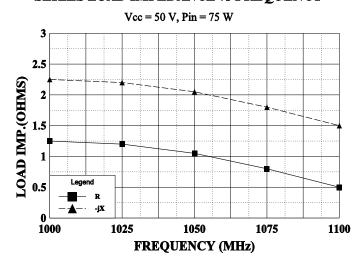
THERMAL RESISTANCE vs PULSE WIDTH



SERIES INPUT IMPEDANCE vs FREQUENCY



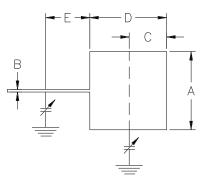
SERIES LOAD IMPEDANCE vs FREQUENCY

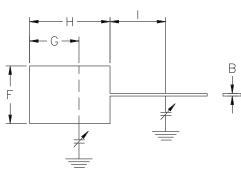


June 1996



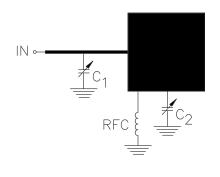
REVISIONS					
ZONE	ZONE REV DESCRIPTION		DATE	APPROVED	

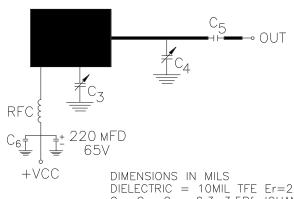




DIM	INCHES		
А	.815		
В	.027		
С	.390		
D	.800		
E	.460		
F	.600		
G	.515		
Н	.839		
1	.580		

TPR 500 TEST CIRCUIT





DIMENSIONS IN MILS DIELECTRIC = 10MIL TFE Er=2.55 C_1 , C_2 , C_4 = 0.3-3.5Pf JOHANSON C_3 = .6-6.5 Pf JOHANSON C_5 , C_6 = 82Pf ATC "A"



cage 0PJR2	DWG NO.	TPR	500	REV A
	SCALE	1/1	SHEET	